

Features

- Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low R_{DS(ON)}
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 20°C/W Junction to Ambient(t≤10s)^(Note 2)
- Thermal Resistance: 55°C/W Junction to Ambient(Steady-State)^(Note 2)
- Thermal Resistance: 1.3°C/W Junction to Case(Steady-State)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-100	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	-28	Α
Pulsed Drain Current ^(Note 3)	I _{DM}	-112	Α
Total Power Dissipation ^(Note 4)	P _D	96	W
Single Pulsed Avalanche Energy ^(Note 5)	E _{AS}	220	mJ

Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The Power dissipation P_{DSM} is based on R_{θJA} t≤10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 5. V_{DD} =50V, R_{G} =25 Ω , L=1mH, I_{AS} =31A.

Internal Structure and Marking Code



P-CHANNEL MOSFET



Gate
J. Gate
J. Drain
Source

DIM	INCHES		MM		NOTE
DIN	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
Κ	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
Μ	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics				I	1	I	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250µA	-100			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V			-1	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , Ι _D =-250μΑ	-1		-2.5	V	
Drain-Source On-Resistance	В	V _{GS} =-10V, I _D =-15A		42	58	mΩ	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-7A		46	65		
Diode Characteristics					•		
Continuous Body Diode Current	I _S				-28	A	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-20A			-1.3	V	
Reverse Recovery Time	t _{rr}	l _s =-5A, dl _⊧ /dt=100A/µs		104		ns	
Reverse Recovery Charge	Q _{rr}	$1_{\rm S}$ 5A, $u_{\rm F}/u_{\rm C}$ -100A/µS		280		nC	
Dynamic Characteristics	•		•		•		
Input Capacitance	C _{iss}			2100			
Output Capacitance	C _{oss}	V _{DS} =-50V,V _{GS} =0V,f=1MHz		236		pF	
Reverse Transfer Capacitance	C _{rss}			48			
Total Gate Charge	Qg			40			
Gate-Source Charge	Q _{gs}	V _{DS} =-50V,V _{GS} =-10V,I _D =-5A		7.8		nC	
Gate-Drain Charge	Q _{gd}			8.6			
Turn-On Delay Time	t _{d(on)}			13			
Turn-On Rise Time	t _r	V _{DS} =-50V, V _{GEN} =-10V,		39		- ns	
Turn-Off Delay Time	t _{d(off)}	R _G =6Ω, I _{DS} =-5A		100.1			
Turn-Off Fall Time	t _f			105.3			





Curve Characteristics





Curve Characteristics







Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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